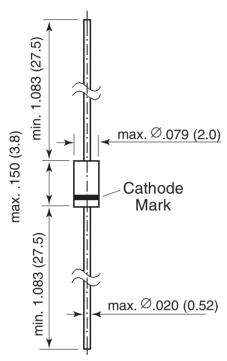
Small-Signal Diode

DO-35 Glass



Dimensions in inches and (millimeters)

Features

- Silicon Epitaxial Planar Diode
- Fast switching diode.
- This diode is also available in other case styles including the SOD-123 case with the type designation 1N4148W, the MiniMELF case with the type designation LL4148, the SOT-23 case with the type designation IMBD4148.

Mechanical Data

Case: DO-35 Glass Case Weight: approx. 0.13g

Maximum Ratings and Thermal Characteristics (TA = 25°C unless otherwise noted)

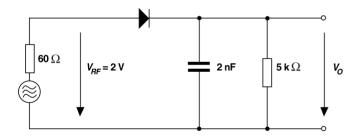
Parameter	Symbol	Limit	Unit	
Reverse Voltage	VR	75	V	
Peak Reverse Voltage	VRM	100	V	
Average Rectified Current Half Wave Rectification with Resistive Load at T _{amb} = 25°C	I _{F(AV)}	150 ¹⁾	mA	
Surge Forward Current at t < 1s and Tj = 25°C	IFSM	500	mA	
Power Dissipation at T _{amb} = 25°C ⁽¹⁾	Ptot	500	mW	
Thermal Resistance Junction to Ambient Air ⁽¹⁾	RөJA	350	°C/W	
Junction Temperature	Tj	175	°C	
Storage Temperature	Ts	-65 to +175	°C	

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Electrical Characteristics (TJ = 25°C unless otherwise noted)

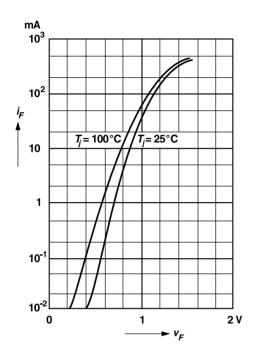
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Breakdown Voltage	V _{(BR)R}	I _R = 100μA	100			V
Forward Voltage	VF	IF = 10mA	_	_	1.0	V
Leakage Current	IR	V _R = 20V V _R = 75V V _R = 20V, T _J = 150°C	_ _ _	_ _ _	25 5 50	nA μA μA
Capacitance	Ctot	VF = VR = 0V	_	_	4	pF
Voltage Rise when Switching ON (tested with 50mA Pulses)	Vfr	$t_p = 0.1 \mu s$, Rise time < 30ns $f_p = 5$ to 100kHz	_	_	2.5	ns
Reverse Recovery Time	trr	$I_F = 10mA$, $I_{R} = 1mA$, $V_R = 6V$, $R_L = 100\Omega$	_	_	4	ns
Rectification Efficiency	ην	f = 100MHz, V _{RF} = 2V	0.45	_	_	_

Rectification Efficiency Measurement Circuit



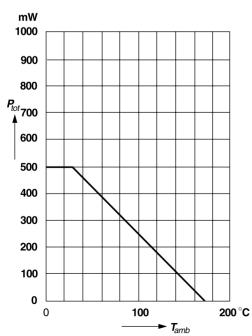
Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Forward characteristics

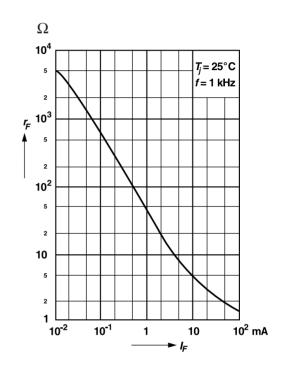


Admissible power dissipation versus ambient temperature

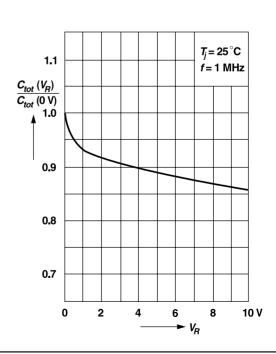
For conditions, see footnote in table "Absolute Maximum Ratings"



Dynamic forward resistance versus forward current

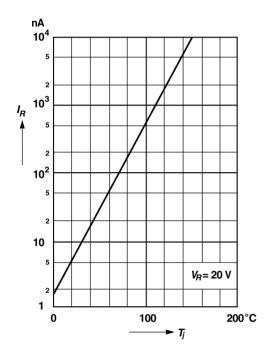


Relative capacitance versus reverse voltage



Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Leakage current versus junction temperature



Admissible repetitive peak forward current versus pulse duration

For conditions, see footnote in table "Absolute Maximum Ratings"

